# IS27LV512 65,536 x 8 LOW VOLTAGE CMOS EPROM



# **NOVEMBER 1997**

# FEATURES

- Single 2.7V to 3.6V power supply
- Fast access time: 90 ns
- JEDEC-approved pinout
- Low power consumption
  - 20 μA (max) standby current
  - 8 mA (max) active current at 5 MHz
- High-speed write programming
  - Typically less than eight seconds
- Industrial and commercial temperature ranges
   available
- Standard 28-pin DIP and TSOP, and 32-pin PLCC packages

# DESCRIPTION

The *ISSI* IS27LV512 is a low voltage, low power, high-speed 512K-bit CMOS (64K-word by 8-bit) CMOS Programmable Read-Only Memory. It utilizes the standard JEDEC pinout making it functionally compatible with the IS27C512 EPROM.

The superior access time combined with low power consumption is the result of innovative design and process technology. If the device is constantly accessed at 5 MHz, the maximum power consumption is increased to 36 mW. These power ratings are significantly lower than the standard IS27C512 EPROM.

The IS27LV512 uses *ISSI*'s write programming algorithm which allows the entire chip to be programmed in typically less than thirty seconds.

This product is available in One-Time Programmable (OTP) PDIP, PLCC, and TSOP packages over commercial and industrial temperature ranges.

# FUNCTIONAL BLOCK DIAGRAM



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A15 🗌	1 •	28	Vcc
A12 🗌	2	27	A14
A7 🗌	3	26	A13
A6 🗌	4	25	A8
A5 🗌	5	24	A9
A4 🗌	6	23	A11
АЗ 🗌	7	22	
A2 🗌	8	21	_ A10
A1 [	9	20	CE (E)
A0 [	10	19	DQ7
	11	18	DQ6
DQ1	12	17	DQ5
DQ2	13	16	DQ4
GND	14	15	DQ3

# **PIN DESCRIPTIONS**

A0-A15	Address Inputs
CE (E)	Chip Enable Input
DQ0-DQ7	Data Inputs/Outputs
$\overline{OE}$ ( $\overline{G}$ )/VPP	Output Enable Input/ Program Voltage Input
Vcc	Power Supply Voltage
GND	Ground
NC	No Internal Connection

32-Pin PLCC

28-Pin TSOP



#### Programming the IS27LV512

Upon delivery, the IS27LV512 has 524,288 bits in the "ONE", or HIGH state. "ZEROs" are loaded into the IS27LV512 through the procedure of programming.

The programming mode is entered when 12.5  $\pm$  0.25V is applied to the  $\overline{OE}$ /VPP pin, Vcc = 6V and  $\overline{CE}$  is at VIL. For programming, the data to be programmed is applied eight bits in parallel to the data output pins.

The write programming algorithm reduces programming time by using 100  $\mu$ s programming pulses followed by a byte verification to determine whether the byte has been successfully programmed. If the data does not verify, an additional pulse is applied for a maximum of 25 pulses. This process is repeated while sequencing through each address of the EPROM.

The write programming algorithm programs and verifies at Vcc = 6V and  $\overline{OE}/V_{PP}$  = 12.5V. After the final address is completed, all byte are compared to the original data with Vcc = 5.25V.

#### **Program Inhibit**

Programming of multiple IS27LV512s in parallel with different data is also easily accomplished. Except for  $\overline{CE}$ , all like inputs of the parallel IS27LV512 may be common. A TTL low-level program pulse applied to an IS27LV512  $\overline{CE}$  input with  $\overline{OE}/V_{PP} = 12.5 \pm 0.25V$  will program that IS27LV512. A high-level  $\overline{CE}$  input inhibits the other IS27LV512 from being programmed.

#### **Program Verify**

A verify should be performed on the programmed bits to determine that they were correctly programmed. The verify should be performed with  $\overline{CE}$  at V<sub>IL</sub> and  $\overline{OE}$ /V<sub>PP</sub> at V<sub>IL</sub>.

#### Auto Select Mode

The auto select mode allows the reading out of a binary code from an EPROM that will identify its manufacturer and type. This mode is intended for use by programming equipment for the purpose of automatically matching the device to be programmed with its corresponding programming algorithm. This mode is functional in the  $25^{\circ}C \pm 5^{\circ}C$  ambient temperature range that is required when programming the IS27LV512.

To activate this mode, the programming equipment must force  $12.0 \pm 0.5$ V on address line A9 of the IS27LV512. Two identifier bytes may then be sequenced from the device outputs by toggling address line A0 from VIL to VIH. All other address lines must be held at VIL during auto select mode.

Byte 0 (A0 = VIL) represents the manufacturer code, and byte 1 (A0 = VIH), the device identifier code. For the IS27LV512, these two identifier bytes are given in the Mode Select table. All identifiers manufacturer and device codes will possess odd parity, with the MSB (DQ7) defined as the parity bit.

#### Read Mode

The IS27LV512 has two control functions, both of which must be logically satisfied in order to obtain data at the outputs. Chip Enable ( $\overline{CE}$ ) is the power control and should be used for device selection. Assuming that addresses are stable, address access time (tACC) is equal to the delay from  $\overline{CE}$  to output (tCE). Output Enable ( $\overline{OE}$ ) is the output control and should be used to get data to the output pins, independent of device selection. Data is available at the outputs toE after the falling edge of  $\overline{OE}$  assuming that  $\overline{CE}$  has been LOW and addresses have been stable for at least tACC – toE.

#### **Standby Mode**

The IS27LV512 has a standby mode which reduces the maximum Vcc active current. It is placed in standby mode when  $\overline{CE}$  is at VIH. The amount of current drawn in standby mode depends on the frequency and the number of address pins switching. The IS27LV512 is specified with 50% of the address lines toggling at 5 MHz. A reduction of the frequency or quantity of address lines toggling will significantly reduce the actual standby current.

#### **Output OR-Tieing**

To accommodate multiple memory connections, a twoline control function is provided to allow for:

- 1. Low memory power dissipation, and
- 2. Assurance that output bus contention will not occur.

It is recommended that  $\overline{CE}$  be decoded and used as the primary device-selecting function, while  $\overline{OE}/V_{PP}$  be made a common connection to all devices in the array and connected to the READ line from the system control bus. This assures that all deselected memory devices are in their low-power standby mode and that the output pins are only active when data is desired from a particular memory device.

#### **System Applications**

During the switch between active and standby conditions, transient current peaks are produced on the rising and falling edges of Chip Enable. The magnitude of these transient current peaks is dependent on the output capacitance loading of the device at a minimum, a 0.1  $\mu$ F ceramic capacitor (high-frequency, low inherent inductance) should be used on each device between Vcc and GND to minimize transient effects. In addition, to overcome the voltage drop caused by the inductive effects of the printed circuit board traces on EPROM arrays, a 4.7  $\mu$ F bulk electrolytic capacitor should be used between Vcc and GND for each eight devices. The location of the capacitor should be close to where the power supply is connected to the array.

#### TRUTH TABLE<sup>(1,2,4)</sup>

Mode		CE	OE/ VPP	A0	A9	Outputs
Read		VIL	VIL	Х	Х	Dout
Output Disable		Х	Vін	Х	Х	Hi-Z
Standby		Vін	Х	Х	Х	Hi-Z
Program		VIL	Vpp	Х	Х	Din
Program Verify		VIL	VIL	Х	Х	Dout
Program Inhibit		Vін	Vpp	Х	Х	Hi-Z
Auto Select <sup>(3,5)</sup>	Manufacturer Code	VIL	VIL	VIL	Vн	D5H
	Device Code	VIL	VIL	Vін	Vн	91H

#### Notes:

1. VH =  $12.0V \pm 0.5V$ .

2.  $X = Either V_{IH} \text{ or } V_{IL}$ .

3. A1-A8 = A10-A15 = VIL.

4. See DC Programming Characteristics for VPP voltage during programming.

5. The IS27LV512 can use the same write algorithm during program as other IS27C512 or IS27512 devices.

# LOGIC SYMBOL



### ABSOLUTE MAXIMUM RATINGS<sup>(1)</sup>

Symbol	Parameter	Value	Unit
Vterm	Terminal Voltage with Respect to GND		
	All pins except A9 and VPP	-0.6 to Vcc + 0.5 <sup>(2)</sup>	V
	VPP	Vcc - 0.3 to 13.5 <sup>(2,3)</sup>	V
	A9	-0.6 to 13.5 <sup>(2,3)</sup>	V
	Vcc	-0.6 to 7.0 <sup>(2)</sup>	V
TA	Ambient Temperature with Power Applied	-65 to +125	°C
TSTG	Storage Temperature (OTP)	-65 to +125	٥C
Tstg	Storage Temperature (All others)	-65 to +150	°C

Notes:

1. Stress greater than those listed under ABSOLUTE MAXIMUM RATINGS may cause permanent damage to the device. This is a stress rating only and functional operation of the device at these or any other conditions above those indicated in the operational sections of this specification is not implied. Exposure to absolute maximum rating conditions for extended periods may affect reliability.

Minimum DC input voltage is -0.5V. During transitions, inputs may undershoot to -2.0V for periods less than 10 ns. Maximum DC voltage on output pins is Vcc + 0.5V which may overshoot to Vcc + 2.0V for periods less than 10 ns.

3. Maximum DC voltage on A9 or VPP may overshoot to +13.5V for periods less than 10 ns.

## **OPERATING RANGE**

Range	Ambient Temperature	Vcc		
Commercial	0°C to +70°C	2.7 to 3.6V		
Industrial <sup>(1)</sup>	–40°C to +85°C	2.7 to 3.6V		

#### Note:

1. Operating ranges define those limits between which the functionally of the device is guaranteed.

## DC ELECTRICAL CHARACTERISTICS<sup>(1,2,3)</sup> (Over Operating Range)

Symbol	Parameter	Test Conditions	Min.	Max.	Unit
Vон	Output HIGH Voltage	Vcc = Min., IoH = $-400 \ \mu A$	2.4	—	V
Vol	Output LOW Voltage	Vcc = Min., IoL = 2.1 mA	—	0.45	V
Viн	Input HIGH Voltage <sup>(4)</sup>		2.0	Vcc + 0.5	V
VIL	Input LOW Voltage <sup>(4)</sup>		-0.3	0.8	V
lu	Input Load Current	$V_{IN} = 0V$ to +Vcc	—	5.0	μΑ
Ilo	Output Leakage Current	Vout = $0V$ to +Vcc	_	10	μΑ

Notes:

1. Vcc must be applied simultaneously or before VPP and removed simultaneously or after VPP. Never try to force VPP LOW to 1V below Vcc. Manufacturer suggests to tie VPP and Vcc together during the READ operation.

2. Caution: the IS27LV512 must not be removed from (or inserted into) a socket when Vcc or VPP is applied.

3. Minimum DC input voltage is -0.5V. During transitions, the inputs may undershoot to -2.0V for periods less than 10 ns.

Maximum DC voltage on output pins is Vcc + 0.5V which may overshoot to Vcc + 2.0V for periods less than 10 ns.

4. Tested under static DC conditions.

### **POWER SUPPLY CHARACTERISTICS**<sup>(1,2,4)</sup> (Over Operating Range)

Symbol	Parameter	Test Conditions		Min.	Max.	Unit
Icc1	Vcc Operating Supply Current <sup>(3)</sup>	Vcc = Max.,	Commercial Industrial	_	8 10	mA
ICCSB0	Vcc CMOS Standby Current	$\overline{CE} \ge V_{CC} - 0.3V$ All pins $\ge V_{CC} - 0.3V$ or $\le 0$ f $\le 5$ MHz	$\label{eq:cellson} \begin{array}{l} \overline{CE} \geq Vcc - 0.3V \\ \mbox{All pins} \geq Vcc - 0.3V \mbox{ or } \leq 0.3V \mbox{ toggling} \\ f \leq 5 \mbox{ MHz} \end{array}$		20	μΑ
ICCSB1	Vcc TTL Standby Current	$\overline{CE} \ge V_{IH}$ All pins = V_{IH} or V_{IL} (TTL level) toggling f $\le 5$ MHz		_	1	mA

Notes:

1. Vcc must be applied simultaneously or before VPP and removed simultaneously or after VPP. Never try to force VPP LOW to 1V below Vcc. Manufacturer suggests to tie VPP and Vcc together during the READ operation.

2. Caution: the IS27LV512 must not be removed from (or inserted into) a socket when Vcc or VPP is applied.

- 3. Icc1 is tested with  $\overline{OE}/V_{PP} = V_{IH}$  to simulate open outputs.
- 4. Minimum DC input voltage is -0.5V. During transitions, the inputs may undershoot to -2.0V for periods less than 10 ns. Maximum DC voltage on output pins is Vcc + 0.5V which may overshoot to Vcc + 2.0V for periods less than 10 ns.

## CAPACITANCE<sup>(1,2,3)</sup>

			D	IP	PLC	C/TSOP	
Symbol	Parameter	Conditions	Тур.	Max.	Тур.	Max.	Unit
CIN	Input Capacitance	$V_{IN} = 0V$	6	10	6	9	pF
Соит	Output Capacitance	Vout = 0V	8	12	6	9	pF
CIN OE/VPP	OE/VPP Capacitance	$\overline{OE}/VPP = 0V$	12	15	12	15	pF

#### Notes:

1. Typical values are for nominal supply voltage.

2. This parameter is only sampled, but not 100% tested.

3. Test conditions:  $T_A = 25^{\circ}C$ , f = 1 MHz.

# SWITCHING TEST CIRCUIT



# SWITCHING TEST WAVEFORM



Notes:

AC Testing:

1. Inputs are driven at 2.4V for a logic "1" and .45V for a logic "0".

2. Input pulse rise and fall times are < 20ns.

#### SWITCHING CHARACTERISTICS<sup>(1,2,3,4)</sup> (Over Operating Range)

JEDEC	Std.			-(	90	-	2	-1	15	
Symbol	Symbol	Parameter	Test Conditions	Min.	Max.	Min.	Max.	Min.	Max.	Unit
<b>t</b> avqa	tacc	Address to Output Delay	$\overline{CE} = \overline{OE} = V_{IL}$ $C_L = C_L 1$	_	90	_	120	_	150	ns
<b>t</b> ELQV	tce	Chip Enable to Output Delay	OE = VIL CL = CL1	_	90	_	120	_	150	ns
<b>t</b> GLQV	toe	Output Enable to Output Delay	$\overline{CE} = V_{IL}$ $C_L = C_L 1$	_	45	_	50	_	65	ns
tеноz, tgнqz	tdf <sup>(2)</sup>	Chip Enable HIGH or Output Enable HIGH, whichever comes first, to Output Float	CL = CL2	0	30	0	35	0	35	ns
tavox	tон	Output Hold from Address, CE or OE whichever occured first		0	_	0	-	0	-	ns

#### Notes:

1. Vcc must be applied simultaneously or before VPP and removed simultaneously or after VPP.

2. This parameter is only sampled, not 100% tested.

3. Caution: The IS27LV512 must not be removed from (or inserted into) a socket or board when VPP or Vcc applied.

4. Output Load: 1 TTL gate and CL = 100 pF

Input Rise and Fall times: 20 ns.

Input Pulse Levels: 0.45 to 2.4V.

Timing Measurement Reference Level: 0.8V to 2.0V for inputs and outputs.



## SWITCHING WAVEFORMS

#### Notes:

1.  $\overline{OE}$  may be delayed up to tACC – to E after the falling edge of  $\overline{CE}$  without impact on tACC. 2. to F is specified from  $\overline{OE}$  or  $\overline{CE}$ , whichever occurs first.

# **DC PROGRAMMING CHARACTERISTICS**<sup>(1,2,3)</sup> (T<sub>A</sub> = $+25^{\circ}C \pm 5^{\circ}C$ )

Symbol	Parameter	Test Conditions	Min.	Max.	Unit
Vон	Output HIGH Voltage During Verify	Іон = -400 μА	2.4		V
Vol	Output LOW Voltage During Verify	loL = 2.1 mA	_	0.45	V
Vін	Input HIGH Voltage		2.0	Vcc + 0.5	V
VIL	Input LOW Voltage (All Inputs)		-0.3	0.8	V
Vн	A9 Auto Select Voltage		11.5	12.5	V
Iц	Input Current (All Inputs)	VIN = VIL OF VIH	_	10.0	μA
lcc	Vcc Supply Current (Program & Verify)		_	50	mA
IPP	VPP Supply Current	$\overline{CE} = VIL, \overline{OE} = VIH$	_	30	mA
Vcc	Supply Voltage		5.75	6.25	V
Vpp	Programming Voltage		12.25	12.75	V

# SWITCH PROGRAMMING CHARACTERISTICS<sup>(1,2,3)</sup> (T<sub>A</sub> = $+25^{\circ}C \pm 5^{\circ}C$ )

JEDEC	Std.				
Symbol	Symbol	Parameter	Min.	Max.	Unit
<b>t</b> AVEL	tas	Address Setup Time	2	—	μs
<b>t</b> ehgl	tоен	OE/VPP Hold Time	2	_	μs
<b>t</b> dvel	tos	Data Setup Time	2	_	μs
<b>t</b> GHAX	tан	Address Hold Time	0	_	μs
<b>t</b> ehdx	tdн	Data Hold Time	2	_	μs
<b>t</b> ehqz	<b>t</b> dfp	CE HIGH to Output Float Delay	0	130	ns
tvps	tvps	VPP Setup Time	2	—	μs
teleh1	tpw	CE Program Pulse Width	95	105	μs
tvcs	tvcs	Vcc Setup Time	2	_	μs
<b>t</b> GLEL	<b>t</b> vr	OE/VPP Recovery Time	2	_	μs
<b>t</b> elqv	tdv	Data Valid from CE		150	ns

#### Notes:

1. Vcc must be applied simultaneously or before VPP and removed simultaneously or after VPP.

2. When programming IS27LV512, a 0.1 μF capacitor is required across VPP and ground to suppress spurious voltage transients which may damage the device.

3. Programming characteristics are sampled but not 100% tested at worst-case conditions.

## **PROGRAMMING ALGORITHM WAVEFORM**<sup>(1,2)</sup>



#### Notes:

- 1. The timing reference level is 0.8V to 2V for inputs and outputs.
- 2. toE and tDFP are characteristics of the device but must be accommodated by the programmer.

# **PROGRAMMING FLOW CHART**



# ORDERING INFORMATION Commercial Range: 0°C to +70°C

Speed (ns)	Order Part Number	Package
90	IS27LV512-90W IS27LV512-90PL IS27LV512-90T	600-mil Plastic DIP PLCC – Plastic Leaded Chip Carrier TSOP
120	IS27LV512-12W IS27LV512-12PL IS27LV512-12T	600-mil Plastic DIP PLCC – Plastic Leaded Chip Carrier TSOP
150	IS27LV512-15W IS27LV512-15PL IS27LV512-15T	600-mil Plastic DIP PLCC – Plastic Leaded Chip Carrier TSOP

# ORDERING INFORMATION

# Industrial Range: -40°C to +85°C

Speed (ns)	Order Part Number	Package
90	IS27LV512-90WI IS27LV512-90PLI IS27LV512-90TI	600-mil Plastic DIP PLCC – Plastic Leaded Chip Carrier TSOP
120	IS27LV512-12WI IS27LV512-12PLI IS27LV512-12TI	600-mil Plastic DIP PLCC – Plastic Leaded Chip Carrier TSOP
150	IS27LV512-15WI IS27LV512-15PLI IS27LV512-15TI	600-mil Plastic DIP PLCC – Plastic Leaded Chip Carrier TSOP



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